# 1-Bit Dual-Supply Non-Inverting Level Translator

The NLSV1T244 is a 1-bit configurable dual-supply voltage level translator. The input  $A_n$  and output  $B_n$  ports are designed to track two different power supply rails,  $V_{CCA}$  and  $V_{CCB}$  respectively. Both supply rails are configurable from 0.9 V to 4.5 V allowing universal low-voltage translation from the input  $A_n$  to the output  $B_n$  port.

### Features

- Wide  $V_{CCA}$  and  $V_{CCB}$  Operating Range: 0.9 V to 4.5 V
- High-Speed w/ Balanced Propagation Delay
- Inputs and Outputs have OVT Protection to 4.5 V
- Non-preferential V<sub>CCA</sub> and V<sub>CCB</sub> Sequencing
- Outputs at 3-State until Active V<sub>CC</sub> is Reached
- Power-Off Protection
- Outputs Switch to 3-State with V<sub>CCB</sub> at GND
- Ultra-Small Packaging: 1.2 mm x 1.0 mm UDFN6
- This is a Pb-Free Device

### **Typical Applications**

• Mobile Phones, PDAs, Other Portable Devices

### Important Information

• ESD Protection for All Pins: HBM (Human Body Model) > 3000 V

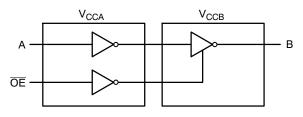
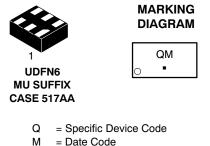


Figure 1. Logic Diagram

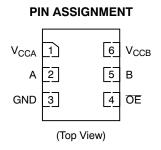


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= Pb-Free Package



### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NLSV1T244MUTBG	UDFN6 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

### **PIN ASSIGNMENT**

PIN	FUNCTION
V <sub>CCA</sub>	Input Port DC Power Supply
V <sub>CCB</sub>	Output Port DC Power Supply
GND	Ground
А	Input Port
В	Output Port
ŌĒ	Output Enable

# MAXIMUM RATINGS

#### Γ Innute

**TRUTH TABLE** 

In	Inputs		
ŌĒ	А	В	
L	L	L	
L	Н	Н	
н	х	3-State	

Symbol	Rating		Value	Condition	Unit
$V_{CCA}, V_{CCB}$	DC Supply Voltage		-0.5 to +5.5		V
VI	DC Input Voltage	Α	-0.5 to +5.5		V
V <sub>C</sub>	Control Input	ŌE	-0.5 to +5.5		V
V <sub>O</sub>	DC Output Voltage (Power Down)	В	-0.5 to +5.5	$V_{CCA} = V_{CCB} = 0$	V
	(Active Mode)	В	-0.5 to +5.5		V
	(Tri-State Mode)	В	-0.5 to +5.5		V
I <sub>IK</sub>	DC Input Diode Current		-20	V <sub>I</sub> < GND	mA
I <sub>OK</sub>	DC Output Diode Current		-50	V <sub>O</sub> < GND	mA
Ι <sub>Ο</sub>	DC Output Source/Sink Current		±50		mA
I <sub>CCA</sub> , I <sub>CCB</sub>	DC Supply Current Per Supply Pin		±100		mA
I <sub>GND</sub>	DC Ground Current per Ground Pin		±100		mA
T <sub>STG</sub>	Storage Temperature		-65 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Мах	Unit
V <sub>CCA</sub> , V <sub>CCB</sub>	Positive DC Supply Voltage		0.9	4.5	V
VI	Bus Input Voltage		GND	4.5	V
V <sub>C</sub>	Control Input	ŌĒ	GND	4.5	V
V <sub>IO</sub>	Bus Output Voltage (Power Down Mode)	В	GND	4.5	V
	(Active Mode)	В	GND	V <sub>CCB</sub>	V
	(Tri-State Mode)	В	GND	4.5	V
T <sub>A</sub>	Operating Temperature Range		-40	+85	°C
Δt / ΔV	Input Transition Rise or Rate V <sub>I</sub> , from 30% to 70% of V <sub>CC</sub> ; V <sub>CC</sub> = 3.3 V $\pm 0.3$ V		0	10	nS

### DC ELECTRICAL CHARACTERISTICS

					-40°C t	o +85°C	
Symbol	Parameter	Test Conditions	V <sub>CCA</sub> (V)	V <sub>CCB</sub> (V)	Min	Max	Unit
VIH	Input HIGH Voltage		3.6 - 4.5	0.9 - 4.5	2.2	_	V
	(A, <del>OE</del> )		2.7 – 3.6		2.0	-	
			2.3 – 2.7		1.6	-	
			1.4 - 2.3	-	0.65 * V <sub>CCA</sub>	-	
			0.9 – 1.4	-	0.9 * V <sub>CCA</sub>	-	
V <sub>IL</sub>	Input LOW Voltage		3.6 - 4.5	0.9 - 4.5	-	0.8	V
	(A, <del>OE</del> )		2.7 – 3.6		-	0.8	1
			2.3 – 2.7		-	0.7	1
			1.4 - 2.3		-	0.35 * V <sub>CCA</sub>	1
			0.9 – 1.4		-	0.1 * V <sub>CCA</sub>	1
V <sub>OH</sub>	Output HIGH Voltage	I <sub>OH</sub> = -100 μA; V <sub>I</sub> = V <sub>IH</sub>	0.9 - 4.5	0.9 - 4.5	$V_{CCB} - 0.2$	-	V
		$I_{OH} = -0.5 \text{ mA}; V_I = V_{IH}$	0.9	0.9	0.75 * V <sub>CCB</sub>	-	1
		$I_{OH} = -2 \text{ mA}; V_I = V_{IH}$	1.4	1.4	1.05	-	1
		$I_{OH} = -6 \text{ mA}; \text{ V}_{I} = \text{V}_{IH}$	1.65	1.65	1.25	-	
			2.3	2.3	2.0	-	1
		I <sub>OH</sub> = -12 mA; V <sub>I</sub> = V <sub>IH</sub>	2.3	2.3	1.8	-	1
			2.7	2.7	2.2	-	
		I <sub>OH</sub> = -18 mA; V <sub>I</sub> = V <sub>IH</sub>	2.3	2.3	1.7	-	
			3.0	3.0	2.4	-	
		$I_{OH} = -24 \text{ mA}; V_I = V_{IH}$	3.0	3.0	2.2	-	
V <sub>OL</sub>	Output LOW Voltage	$I_{OL}$ = 100 $\mu$ A; V <sub>I</sub> = V <sub>IL</sub>	0.9 - 4.5	0.9 - 4.5	-	0.2	V
		$I_{OL}$ = 0.5 mA; $V_I$ = $V_{IH}$	1.1	1.1	-	0.3	
		I <sub>OL</sub> = 2 mA; V <sub>I</sub> = V <sub>IH</sub>	1.4	1.4	-	0.35	1
		$I_{OL} = 6 \text{ mA}; V_I = V_{IL}$	1.65	1.65	-	0.3	1
		I <sub>OL</sub> = 12 mA; V <sub>I</sub> = V <sub>IL</sub>	2.3	2.3	-	0.4	
			2.7	2.7	-	0.4	
		I <sub>OL</sub> = 18 mA; V <sub>I</sub> = V <sub>IL</sub>	2.3	2.3	-	0.6	1
			3.0	3.0	-	0.4	1
		$I_{OL}$ = 24 mA; $V_I$ = $V_{IL}$	3.0	3.0	-	0.55	
Ι	Input Leakage Current	$V_I = V_{CCA}$ or GND	0.9 - 4.5	0.9 - 4.5	-1.0	1.0	μA
I <sub>OFF</sub>	Power-Off Leakage Current	<u>OE</u> = 0 V	0 0.9 – 4.5	0.9 – 4.5 0	-1.0 -1.0	1.0 1.0	μA
I <sub>CCA</sub>	Quiescent Supply Current		0.9 - 4.5	0.9 - 4.5	-	1.0	μA
I <sub>CCB</sub>	Quiescent Supply Current	$V_{I} = V_{CCA}$ or GND; $I_{O} = 0, V_{CCA} = V_{CCB}$	0.9 - 4.5	0.9 - 4.5	-	1.0	μA
CCA + I <sub>CCB</sub>	Quiescent Supply Current		0.9 – 4.5	0.9 – 4.5	-	2.0	μA
$\Delta I_{CCA}$	Increase in $I_{CC}$ per Input Voltage, Other Inputs at $V_{CCA}$ or GND	$V_{I} = V_{CCA} - 0.6 V;$ $V_{I} = V_{CCA}$ or GND	4.5 3.6	4.5 3.6	-	10 5.0	μΑ
$\Delta I_{CCB}$	Increase in $I_{CC}$ per Input Voltage, Other Inputs at $V_{CCA}$ or GND	$V_{I} = V_{CCA} - 0.6 V;$ $V_{I} = V_{CCA}$ or GND	4.5 3.6	4.5 3.6	-	10 5.0	μA
I <sub>OZ</sub>	I/O Tri-State Output Leakage Current	$T_A = 25^{\circ}C, \overline{OE} = 0 V$	0.9 - 4.5	0.9 - 4.5	-1.0	1.0	μA

### TOTAL STATIC POWER CONSUMPTION (I<sub>CCA</sub> + I<sub>CCB</sub>)

					-40°C t	o +85°C					
		V <sub>CCB</sub> (V)									
	4.5 3.3 2.8 1.8 0.9										
V <sub>CCA</sub> (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
4.5		2		2		2		2		< 1.5	μA
3.3		2		2		2		2		< 1.5	μA
2.8		< 2		< 1		< 1		< 0.5		< 0.5	μA
1.8		< 1		< 1		< 0.5		< 0.5		< 0.5	μA
0.9		< 0.5		< 0.5		< 0.5		< 0.5		< 0.5	μA

NOTE: Connect ground before applying supply voltage V<sub>CCA</sub> or V<sub>CCB</sub>. This device is designed with the feature that the power-up sequence of V<sub>CCA</sub> and V<sub>CCB</sub> will not damage the IC.

### **AC ELECTRICAL CHARACTERISTICS**

				-40°C to +85°C									
				V <sub>CCB</sub> (V)									
			4	.5	3	.3	2	.8	1	.8	1	.2	
Symbol	Parameter	V <sub>CCA</sub> (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation	4.5		1.6		1.8		2.0		2.1		2.3	nS
t <sub>PHL</sub> (Note 1)	Delay,	3.3		1.7		1.9		2.1		2.3		2.6	
(11010-1)	A to B	2.8		1.9		2.1		2.3		2.5		2.8	
		1.8		2.1		2.4		2.5		2.7		3.0	
		1.2		2.4		2.7		2.8		3.0		3.3	
t <sub>PZH</sub> ,	Output	4.5		2.6		3.8		4.0		4.1		4.3	nS
t <sub>PZL</sub> (Note 1)	Enable,	3.3		3.7		3.9		4.1		4.3		4.6	
(Note T)	O to B	2.5		3.9		4.1		4.3		4.5		4.8	
		1.8		4.1		4.4		4.5		4.7		5.0	
		1.2		4.4		4.7		4.8		5.0		5.3	
t <sub>PHZ</sub> ,	Output	4.5		2.6		3.8		4.0		4.1		4.3	nS
t <sub>PLZ</sub> (Note 1)	Disable,	3.3		3.7		3.9		4.1		4.3		4.6	
(Note T)	OE to B	2.5		3.9		4.1		4.3		4.5		4.8	
		1.8		4.1		4.4		4.5		4.7		5.0	
		1.2		4.4		4.7		4.8		5.0		5.3	
t <sub>OSHL</sub> ,	OSLH Output	4.5		0.15		0.15		0.15		0.15		0.15	nS
t <sub>OSLH</sub> (Note 1)		3.3		0.15		0.15		0.15		0.15		0.15	
	Tim	2.5		0.15		0.15		0.15		0.15		0.15	
		1.8		0.15		0.15		0.15		0.15		0.15	
		1.2		0.15		0.15		0.15		0.15		0.15	

1. Propagation delays defined per Figure 2.

CAPACITANCE

Symbol	Parameter	Test Conditions	Typ (Note 2)	Unit
C <sub>IN</sub>	Control Pin Input Capacitance	$V_{CCA}$ = $V_{CCB}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CCA/B}$	3.5	pF
C <sub>I/O</sub>	I/O Pin Input Capacitance	$V_{CCA}$ = $V_{CCB}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CCA/B}$	5.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CCA}$ = $V_{CCB}$ = 3.3 V, $V_{I}$ = 0 V or $V_{CCA},f$ = 10 MHz	5.0	pF

2. Typical values are at  $T_A = +25^{\circ}C$ . 3.  $C_{PD}$  is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from:  $I_{CC(operating)} \cong C_{PD} \times V_{CC} \times f_{IN}$  where  $I_{CC} = I_{CCA} + I_{CCB}$ .

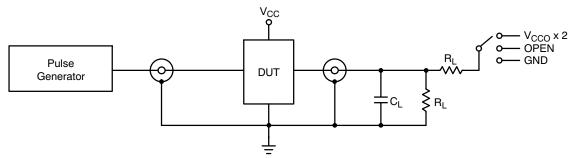
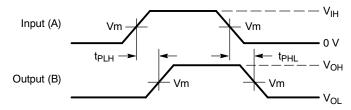
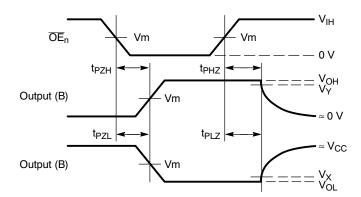


Figure 2. AC (Propagation Delay) Test Circuit

Test	Switch
t <sub>PLH</sub> , t <sub>PHL</sub>	OPEN
t <sub>PLZ</sub> , t <sub>PZL</sub>	V <sub>CCO</sub> x 2
t <sub>PHZ</sub> , t <sub>PZH</sub>	GND
$C_L$ = 15 pF or equivalent (include $R_L$ = 2 k $\Omega$ or equivalent $Z_{OUT}$ of pulse generator = 50 $\Omega$	es probe and jig capacitance)



Waveform 1 – Propagation Delays  $t_R$  =  $t_F$  = 2.0 ns, 10% to 90%; f = 1 MHz;  $t_W$  = 500 ns

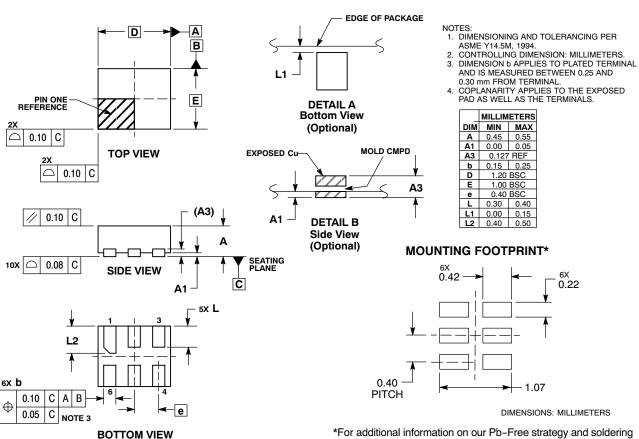


Waveform 2 – Output Enable and Disable Times  $t_{R}$  =  $t_{F}$  = 2.0 ns, 10% to 90%; f = 1 MHz;  $t_{W}$  = 500 ns

		V <sub>CC</sub>									
Symbol	3.0 V – 4.5 V	2.3 V – 2.7 V	1.65 V – 1.95 V	1.4 V – 1.6 V	0.9 V – 1.3 V						
V <sub>mA</sub>	V <sub>CCA</sub> /2										
V <sub>mB</sub>	V <sub>CCB</sub> /2										
V <sub>X</sub>	V <sub>OL</sub> x 0.1										
V <sub>Y</sub>	V <sub>OH</sub> x 0.9										

#### PACKAGE DIMENSIONS

UDFN6 1.2 x 1.0, 0.4P CASE 517AA-01 ISSUE C



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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